

Description:

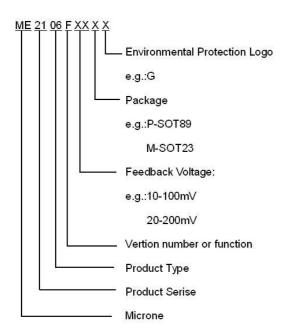
ME2106 Series is a PFM Step-up DC/DC driver IC with invariant current, design for LED applications. Thought the external resistance, output current reach 0mA~500mA.

A low ripple, high efficiency step-up DC/DC converter can be constructed of ME2106xx with only three external components. Also available is a CE (chip enable) function that reduce power consumption.

Features:

- Low start voltage: 0.8V (at lout=1mA)
- Output Current range: 0~500mA
- Output Current accuracy: ±10%
- Only inductors, capacitors, Schottky diodes, resistors and so few external components
- High Efficiency: 82%(Type)
- PACKAGE: SOT-23-5, SOT-89-5

Selection Guide:

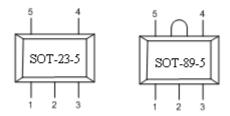


Applications:

- Power source for high-power LED
- Power source for invariant current



Pin configuration:

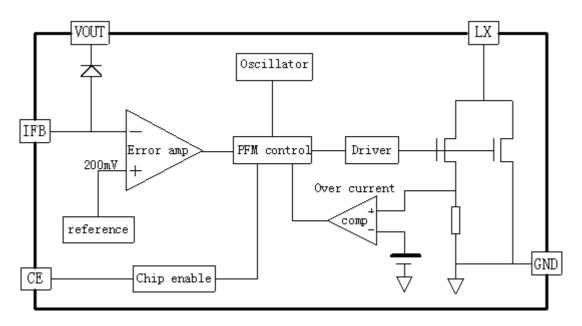


Pin Assignment:

ME2106Fxx

PIN Number		PIN NAME	FUNCTION			
SOT-23-5	SOT-89-5	FIN NAIVIE	FUNCTION			
1	3	CE	Chip enable			
2	2	Vout	Output voltage monitor, IC internal power supply			
3	1	FB	Feedback			
4	5	GND	Ground			
5	4	Lx	Switch			

Block Diagram:





Absolute Maximum Ratings:

PARAMETE	R	SYMBAL	RATINGS	UNITS
V _{IN} Input Volta	age	V_{IN}	0.3~6.5	V
Lx Pin volta	ge	V_{LX}	0.3~Vout+0.3	V
CE Pin volta	ge	V_{CE}	0.3~Vout+0.3	V
IFB output volt	age	V_{IFB}	0.3~Vout+0.3	V
Lx Pin current		I_{LX}	1.5	mA
Continuous Total Power Dissipation	SOT-23-5	Pd	300	mW
	SOT-89-5	Pd	500	mW
Maximum Operating Ambient Temperature		T _{max}	150	°C
Operating Ambient Te	mperature	T _{Opr}	-20~+85	$^{\circ}\mathbb{C}$
Storage Temper	ature	T _{stg}	-40~+125	$^{\circ}$ C
Soldering temperatur	e and time	T _{solder}	260℃, 10s	

Recommend work conditions:

PARAMETER	MIN	RECOMMEND	MAX	UNITS
Input voltage	0.8		Vout	V
Inductance	10	15	100	μH
Input inductance	0	≥22		μF
output inductance	47	100	220	μF
Operating Ambient Temperature	-20		85	$^{\circ}$



Electrical Characteristics:

ME2106F (Measuring conditions: V_{IN} =2.5V, V_{CE} = V_{OUT} =3.3 V, R= 33 Ω , T_A = 25 $^{\circ}$ C.Unless otherwise specified)

SYMBOL	PARAMETER	CONDITIONS	MIN	TYP	MAX	UNITS
V _{OUT}	feedback Voltage	I _{OUT} =100mA	180	200	220	mV
V _{start}	Starup Voltage	I _{OUT} =1mA, V _{IN} : 0→2V		0.8	0.9	V
V_{hold}	holding Voltage	I _{OUT} =1mA, V _{IN} : 2→0V	0.6	0.7		V
I _{DD2}	Supply Current	V _{CE} =V _{IFB} =V _{OUT} =3.3V			50	μA
I _{LXleak}	Lx Leakage Current	$V_{CE}=V_{LX}=V_{OUT}=V_{IFB}=3.3V$			1	μA
F _{osc}	Oscillation Frequency	V _{IFB} =0		300		kHz
Maxdty	Duty Ratio	On(V _{LX} "L")side	77	79	82	%
η	Efficiency	I _{OUT} =250mA		82		%
V _{CEH}	CE is "H",input voltage	V _{CE} : 0→2V (up to work slowly with the chip)	0.6			V
V _{CEL}	CE is "L",input voltage	V _{CE} : 2V→0 (down to work off slowly with the chip)			0.4	V

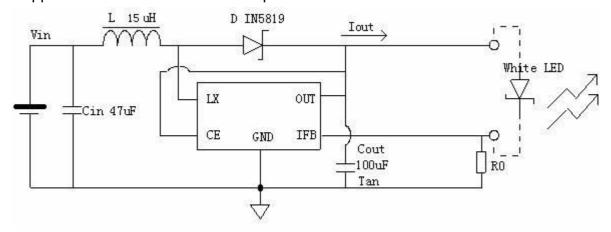
Notes:

- 1. Diode: Schottky diode (forward voltage drop: 0.3V, 0.3A), such as IN5817 or 1N5819
- 2. Inductor: $15 \mu H (R<0.5 \Omega)$
- 3. Capacitor: $100 \,\mu\,F$ (Tantalum type)
- 4. V_{IFB} (SET) is feedback voltage of the chip set up , is the first parameter of the table ,such as 200mV $_{\circ}$

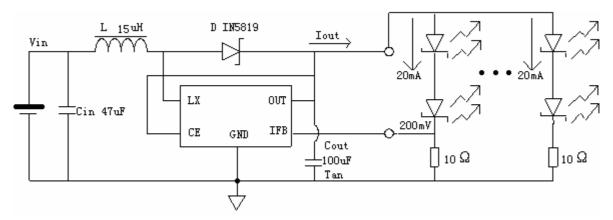


Typical Applications:

Application of constant current output



(A) Drive one white light LED with 1W



(B) Drive more serial two parallel white light LED with low power

Suggestions:

- You can increase the output capacitor properly for improve to the characteristic of the output invariant current (for example: 150uF or 200uF).
- > To avoid the feedback voltage excursion, please wear the ring with static electricity and the electric iron connect to ground when the soldering.



Operation:

ME2106 is a DC/DC step-up converter with voltage type , PFM control mode , output invariablenes current. It has only three Peripheral components that is a inductor 、a output capacitor、a schottky diode and a resistor with set-up output current, that can afford to a invariant output current between 0 and 500mA .Rc set-up method: If the output current is lout, that $Rc=\frac{V_{IFB}}{Iout}$ or example, want to the current value of 100mA , select the chip of VIFB=200mV, that $Rc=200\text{mV}/100\text{mA}=2\Omega$ or $Rc=200\text{mV}/100\text{mA}=2\Omega$

Selection of Peripheral Components and Application Notes

Sum up , inductor , schottky diode would be affect the switching efficiency , capacitor and inductor would be affect the output ripple. Choose such an inductor, capacitor, schottky diode that have high switching efficiency, low ripple, low noises.

Before discussion, define to
$$D \equiv \frac{Vout - Vin}{Vout}$$
.

First, selection of inductor

Make sure DC-DC can natural work firstly in the model of the minimum continuous current that is Lmin, ${\rm Lmin} \ge \frac{D(1-D)^2 R_L}{2\,f}$.

This formula deduce that ignoring the autoecious resistor and a diode with the forward voltage drop, but the actual value is still big. If the inductance less than Lmin, inductor will reach magnetic saturation, efficiency will greatly drop, and hardly output steady voltage.

Secondly, considering the current ripple of the inductor, ignoring the autoecious parameter in the mode of continuous current.

$$\Delta I = \frac{D \cdot Vin}{Lf}$$
, $I_{max} = \frac{Vin}{(1-D)^2 R_I} + \frac{DVin}{2Lf}$

When "L" is too small, will lead to high current ripple of the inductor , and the maximum current of the inductor , schottky diode , power tube of the chip are excessive .

Thirdly, generally speaking, not considering efficiency, small inductor can drive load more then large inductor. But in the same load conditions, large inductor with the current ripple and the maximum current value are small. So the large inductor should be able to start up circuit in the low input voltage.

Use inductor with an inductance of $10\mu H$ or more ,it's ensure to normal work . If output port has load with output large current (for example: output current is more than 50mA), for improving to efficiency, suggest to use large inductor. At the same time, in the large load, the resistor is in series with the inductor that will affect the switching efficiency. Supposed , the resistor is rL, R_{load} , that the power consumption as follow:

$$\Delta \eta \approx \frac{r_L}{R_{local}(1-D)^2}$$

For example, input 1.5V, output 3.0V, load 20 Ω (150mA),rL=0.5 Ω ,efficiency loss 10% . Considering, suggest to use an inductance of 15 uH , rL<0.5 Ω .



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second, selection of capacitor

No considering the inductor with equivalent series resistor(ESR), output voltage ripple is:

$$r = \frac{\Delta Vout}{Vout} = \frac{D}{R_{load}Cf}$$

considering the inductor's ESR, the output ripple will be increase:

$$r' = r + \frac{\operatorname{Im} ax \bullet R_{ESR}}{Vout}$$

Suggest to use Tantalum type with the low ESR or more parallel-resistor.

Third, selection of diode

It is recommended that the diode have great effect to DC-DC efficiency, we suggest to use schottky diode with the lower positive turn-on voltage and the lower corresponsive time. For example, 1N5817、1N5819.

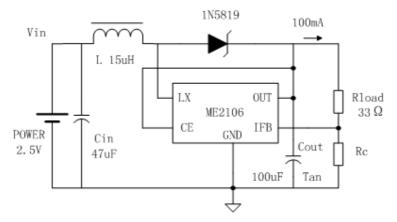
Fourth, selection of input capacitor

Power supply is stably, even if no input capacitor, DC-DC can output voltage with the lower ripple and the lower noise. But we suggest to connect with the capacitor of 10uF or more when the power supply was far away DC-DC, for minish the output noise.

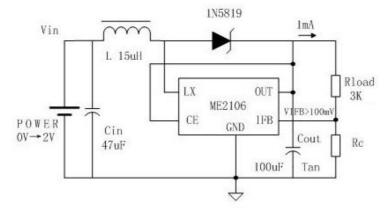


Testing circuit:

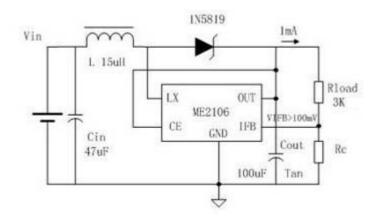
(1) Test foldback voltage



(2) Test startup voltage

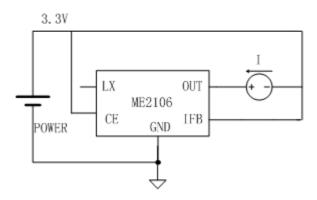


(3) Test holding voltage

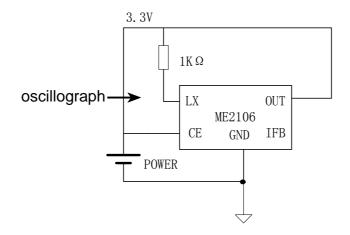




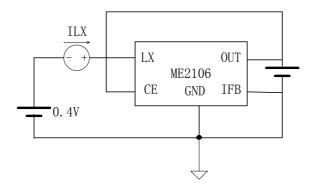
(4) Test supply current



(5) Test Oscillation Frequency and Duty Ratio

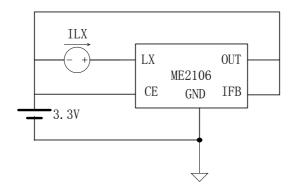


(6)Test switching current

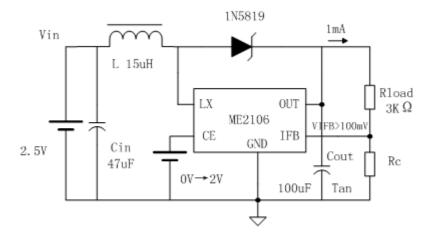




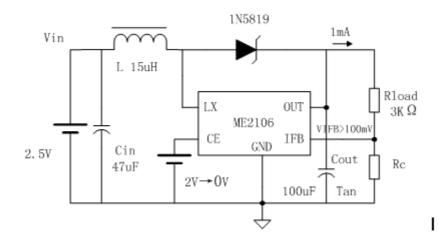
(7) Test switch leakage current



(8) Test CE high voltage



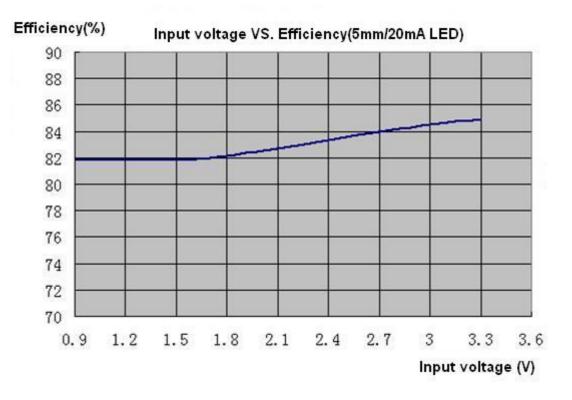
(9) Test CE low voltage

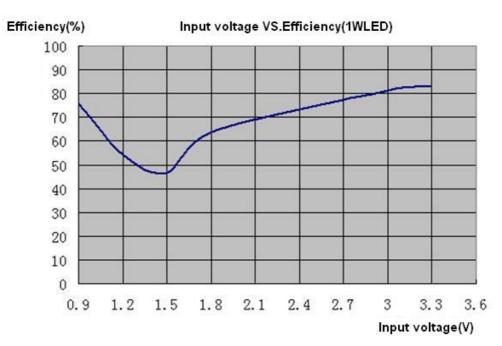




Operating Characteristics:

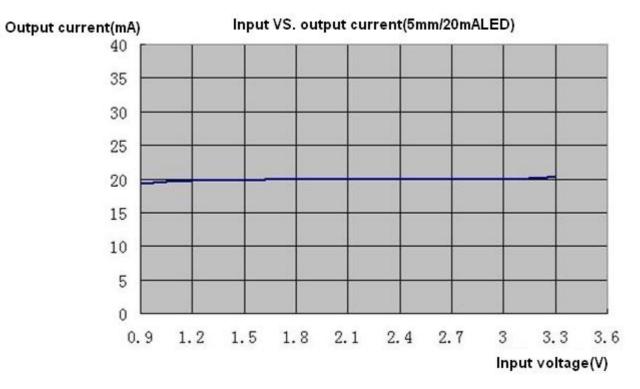
(1)Input VoltageVS. Efficiency





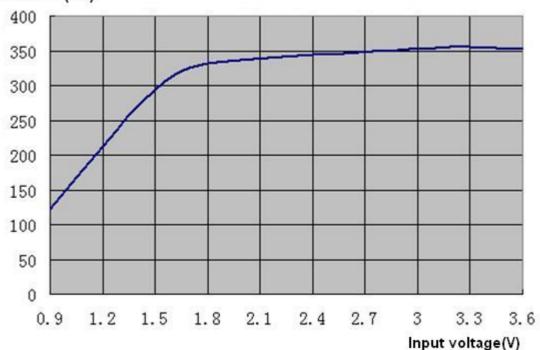


(2)Input voltage VS.output current



Input voltageVS.output current(1WLED)

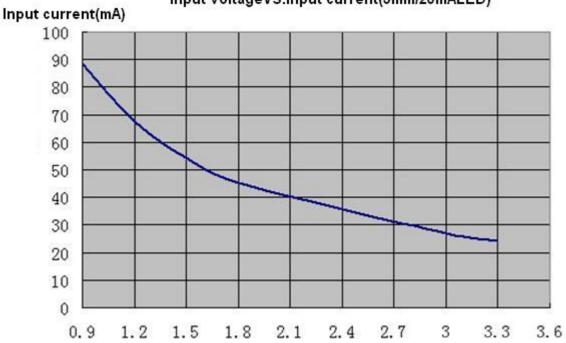






(3)Input voltage VS. Input currnet

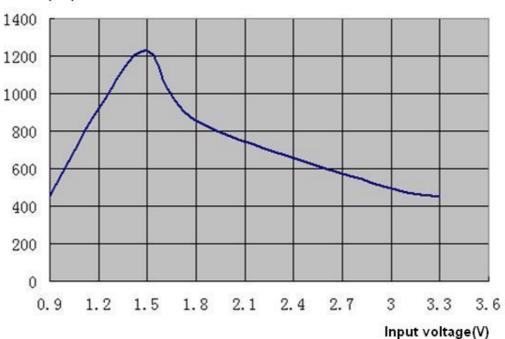
Input voltageVS.Input current(5mm/20mALED)



Input voltage VS. Input current(1WLED)

Input voltage(V)

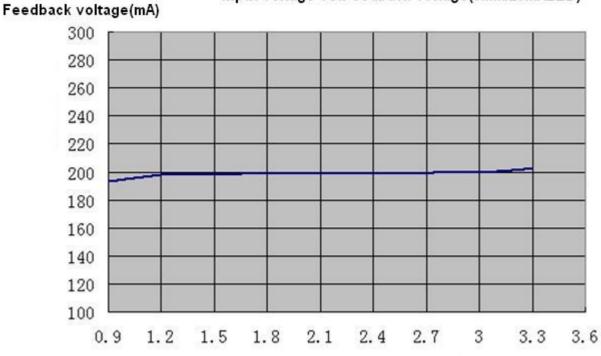
Input current(mA)





(4) Input volatage VS.Feedback voltage

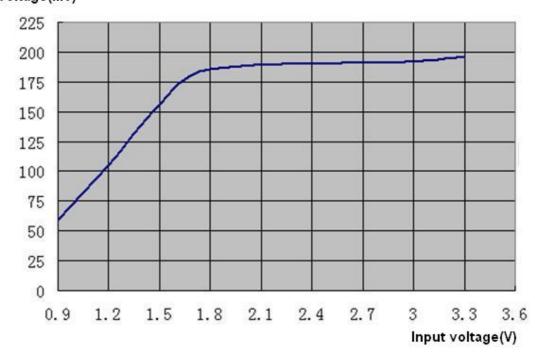
Input voltage VS.Feedback voltage(5mm/20mALED)



Input voltage(V)

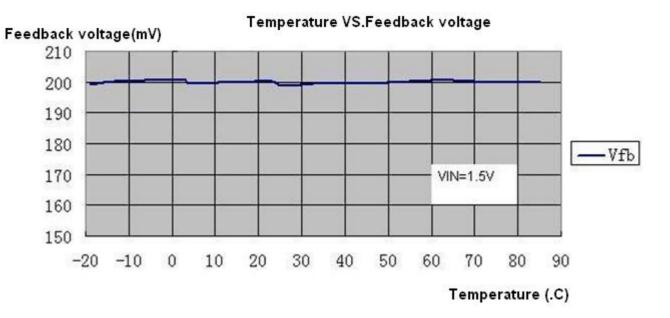
Feedback voltage(mV)

Input voltage VS.Feedback voltage(1WLED)

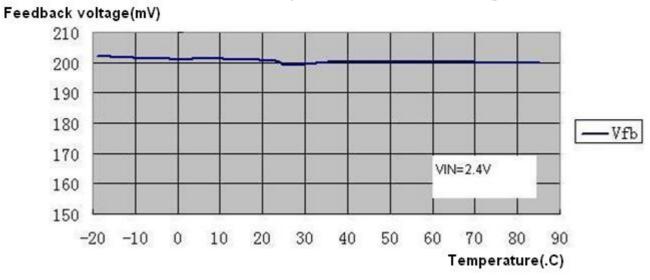




(5) Temperature VS. Feedback Voltage(tow Parallel 5mm/20mA LED)

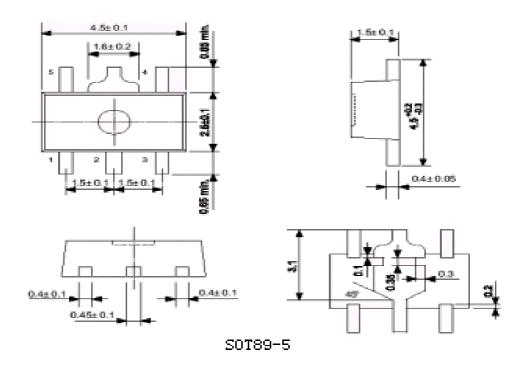


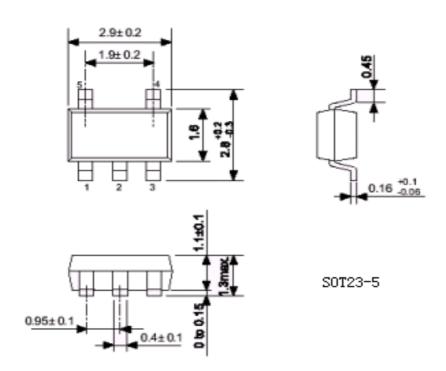
Temperature VS. Feedback voltage





Package Dimensions:







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